5. I/O Features in Cyclone V Devices



This chapter provides details about the features of the Cyclone[®] V I/O elements (IOEs) and how the IOEs work in compliance with current and emerging I/O standards and requirements.

Cyclone V I/Os support a wide range of features:

- Single-ended, non voltage-referenced, and voltage-referenced I/O standards
- Low-voltage differential signaling (LVDS), scalable low-voltage signaling (SLVS), RSDS, mini-LVDS, HSTL, HSUL, and SSTL I/O standards
- Serializer / deserializer (SERDES)
- Programmable output current strength
- Programmable slew-rate
- Programmable bus-hold
- Programmable pull-up resistor
- Programmable pre-emphasis
- Programmable I/O delay
- Programmable voltage output differential (V_{OD})
- Open-drain output
- On-chip series termination (R_S OCT)
- On-chip parallel termination (R_T OCT)
- On-chip differential termination (R_D OCT)
- High-speed differential I/O support
- The information in this chapter is applicable to all Cyclone V variants, unless noted otherwise.

This chapter contains the following sections:

- "I/O Standards Support" on page 5–2
- "Design Considerations" on page 5–4
- "I/O Banks" on page 5–8
- "IOE Features" on page 5–13
- "Programmable IOE Features" on page 5–16
- "OCT Schemes" on page 5–19

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- "I/O Standards Termination Schemes" on page 5–27
- "High-Speed Differential I/O Interfaces" on page 5–36
- "LVDS Channels and Dedicated Circuitry" on page 5–40
- "Fractional PLLs and Cyclone V Clocking" on page 5–44
- "Differential Transmitter" on page 5–45
- "Differential Receiver" on page 5–49
- "Source-Synchronous Timing Budget" on page 5–56

I/O Standards Support

Table 5–1 lists the supported I/O standards and typical power supply values

Table 5–1. Cyclone V I/O Standards and Voltage Levels ⁽¹⁾ (Part 1 of 2)

		V _{CCI}	₀ (V)	V _{CCPD} (V)	V _{RFF} (V)	V _{TT} (V)
I/O Standard	Standard Support	Input Operation	Output Operation	(Pre-Driver Voltage)	(Input Ref Voltage)	(Board Termination Voltage)
3.3-V LVTTL/3.3-V LVCMOS ⁽²⁾	JESD8-B	3.3/3.0/2.5	3.3	3.3	—	—
3.0-V LVTTL/3.0-V LVCMOS ⁽²⁾	JESD8-B	3.0/2.5	3.0	3.0	—	—
2.5-V LVCMOS ⁽²⁾	JESD8-5	3.0/2.5	2.5	2.5	—	—
1.8-V LVCMOS ^{(2), (3)}	JESD8-7	1.8/1.5	1.8	2.5	—	—
1.5-V LVCMOS ⁽²⁾	JESD8-11	1.8/1.5	1.5	2.5	—	—
1.2-V LVCMOS	JESD8-12	1.2	1.2	2.5	—	—
3.0-V PCI ⁽⁴⁾	PCI Rev. 2.2	3.0	3.0	3.0	—	—
3.0-V PCI-X ^{(4), (5)}	PCI-X Rev. 1.0	3.0	3.0	3.0	—	—
SSTL-2 Class I	JESD8-9B	(6)	2.5	2.5	1.25	1.25
SSTL-2 Class II	JESD8-9B	(6)	2.5	2.5	1.25	1.25
SSTL-18 Class I ⁽³⁾	JESD8-15	(6)	1.8	2.5	0.90	0.90
SSTL-18 Class II ⁽³⁾	JESD8-15	(6)	1.8	2.5	0.90	0.90
SSTL-15 Class I ⁽³⁾	_	(6)	1.5	2.5	0.75	0.75
SSTL-15 Class II ⁽³⁾	—	(6)	1.5	2.5	0.75	0.75
SSTL-15	JESD79-3D	(6)	1.5	2.5	0.75	(7)
SSTL-135 ⁽³⁾	—	(6)	1.35	2.5	0.675	(7)
SSTL-125 ⁽³⁾	—	(6)	1.25	2.5	0.625	(7)
1.8-V HSTL Class I	JESD8-6	(6)	1.8	2.5	0.90	0.90
1.8-V HSTL Class II	JESD8-6	(6)	1.8	2.5	0.90	0.90
1.5-V HSTL Class I ⁽²⁾	JESD8-6	(6)	1.5	2.5	0.75	0.75
1.5-V HSTL Class II ⁽²⁾	JESD8-6	(6)	1.5	2.5	0.75	0.75
1.2-V HSTL Class I	JESD8-16A	(6)	1.2	2.5	0.6	0.6
1.2-V HSTL Class II	JESD8-16A	(6)	1.2	2.5	0.6	0.6
HSUL-12 ⁽³⁾	—	(6)	1.2	2.5	0.6	(7)
Differential SSTL-2 Class I	JESD8-9B	(6)	2.5	2.5	_	1.25

		V _{cci}	₀ (V)	V _{CCPD} (V)	V _{RFF} (V)	V _{TT} (V)
I/O Standard	Standard Support	Input Operation	Output Operation	Voltage)	(Input Ref Voltage)	(Board Termination Voltage)
Differential SSTL-2 Class II	JESD8-9B	(6)	2.5	2.5	—	1.25
Differential SSTL-18 Class I	JESD8-15	(6)	1.8	2.5	—	0.90
Differential SSTL-18 Class II	JESD8-15	(6)	1.8	2.5	—	0.90
Differential SSTL-15 Class I	—	(6)	1.5	2.5	—	0.75
Differential SSTL-15 Class II	—	(6)	1.5	2.5	—	0.75
Differential 1.8-V HSTL Class I	JESD8-6	(6)	1.8	2.5	—	0.90
Differential 1.8-V HSTL Class II	JESD8-6	(6)	1.8	2.5	—	0.90
Differential 1.5-V HSTL Class I	JESD8-6	(6)	1.5	2.5	—	0.75
Differential 1.5-V HSTL Class II	JESD8-6	(6)	1.5	2.5	—	0.75
Differential 1.2-V HSTL Class I	JESD8-16A	(6)	1.2	2.5	—	0.60
Differential 1.2-V HSTL Class II	JESD8-16A	(6)	1.2	2.5	_	0.60
Differential SSTL-15	JESD79-3D	(6)	1.5	2.5	—	(7)
Differential SSTL-135	—	(6)	1.35	2.5	—	(7)
Differential SSTL-125	—	(6)	1.25	2.5	—	(7)
Differential HSUL-12	—	(6)	1.2	2.5	—	(7)
LVDS	ANSI/TIA/EIA-644	(6)	2.5	2.5	—	—
RSDS	—	(6)	2.5	2.5	—	—
Mini-LVDS		(6)	2.5	2.5		—
LVPECL ⁽⁸⁾	—	(6)	—	2.5	—	—
SLVS ⁽⁹⁾	JESD8-13	(6)	_	2.5	_	_

Table 5–1. Cyclone V I/O Standards and Voltage Levels ⁽¹⁾ (Part 2 of 2)

Notes to Table 5-1:

(1) You cannot assign SSTL, HSTL, and HSUL outputs on VREF pins, even if there are no SSTL, HSTL, and HSUL inputs in the bank.

(2) Supported in the hard processor system (HPS) column I/Os.

(3) Supported in the HPS row I/Os.

(4) The 3.3 V PCI and PCI-X I/O standards are not supported.

(5) **PCI-X** does not meet the PCI-X I-V curve requirement at the linear region.

(6) Single-ended HSTL/SSTL/HSUL, differential SSTL/HSTL/HSUL, and LVDS input buffers are powered by V_{CCPD}.

(7) This I/O standard typically does not require board termination.

(8) The support for the LVPECL I/O standard is only for input clock operation.

(9) The support for the SLVS I/O standard is only for input operation.

Design Considerations

There are several considerations that require your attention to ensure the success of your designs.



For more information about absolute maximum rating and maximum allowed overshoot during transitions, refer to the *Cyclone V Device Datasheet*.

I/O Bank Restrictions

The following sections provide guidelines for mixing non-voltage-referenced and voltage-referenced I/O standards in the devices.

Non-Voltage-Referenced Standards

Each Cyclone V I/O bank has its own VCCIO pins and supports only one V_{CCIO} (1.2, 1.25, 1.35, 1.5, 1.8, 2.5, 3.0, or 3.3 V). An I/O bank can simultaneously support any number of input signals with different I/O standard assignments if the I/O standards support the V_{CCIO} level of the I/O bank.

For output signals, a single I/O bank supports non-voltage-referenced output signals that drive at the same voltage as V_{CCIO} . Because an I/O bank can only have one V_{CCIO} value, it can only drive out the value for non-voltage-referenced signals.

For example, an I/O bank with a 2.5-V V_{CCIO} setting can support 2.5-V standard inputs and outputs, and **3.0-V LVCMOS** inputs only.

Voltage-Referenced Standards

To accommodate voltage-referenced I/O standards, each Cyclone V I/O bank contains a dedicated VREF pin. Each bank can have only a single V_{CCIO} voltage level and a single voltage reference (V_{REF}) level.

An I/O bank featuring single-ended or differential standards can support different voltage-referenced standards if the V_{CCIO} and V_{REF} are the same levels.

Voltage-referenced bidirectional and output signals must be the same as the $\rm V_{\rm CCIO}$ voltage of the I/O bank.

For example, you can place only SSTL-2 output pins in an I/O bank with a 2.5-V $V_{\text{CCIO}}.$

Mixing Voltage-Referenced and Non-Voltage-Referenced Standards

An I/O bank can support voltage-referenced and non-voltage-referenced pins by applying each of the rule sets individually.

First example: an I/O bank can support **SSTL-18** inputs and outputs, and 1.8-V inputs and outputs with a 1.8-V $V_{\rm CCIO}$ and a 0.9-V $V_{\rm REF}$

Second example: an I/O bank can support 1.5-V standards, 1.8-V inputs (but not outputs), and 1.5-V HSTL I/O standards with a 1.5-V V_{CCIO} and 0.75-V V_{REF}.

V_{CCPD} **Restriction**

One VCCPD pin is shared in a group of I/O banks. The V_{CCPD} grouping on Cyclone V are as follows. Each line item is a separate group:

- BANK 3A
- BANK3B + BANK4A
- BANK5A
- BANK5B
- BANK6A
- BANK7A + BANK8A

First example: if one I/O bank in a group uses 3.0-V V_{CCPD}, other I/O banks in the same group must also use 3.0-V V_{CCPD}. This would also require each I/O bank in the same group to also use a 3.0-V V_{CCIO}.

Second example: if one I/O bank in a group uses a 2.5-V V_{CCPD}, other I/O banks in the same group must also use 2.5-V V_{CCPD}. However, each I/O bank can use different V_{CCIO} voltages provided they are 1.2, 1.25, 1.35, 1.5, 1.8, or 2.5 V.

V_{CCIO} Restriction

When planning the I/O bank usage, you must ensure the $V_{\rm CCIO}$ voltage is compatible with the $V_{\rm CCPD}$ voltage of the same bank. Some banks may share the same <code>VCCPD</code> power pin. This limits the possible $V_{\rm CCIO}$ voltages that can be used on banks that share <code>VCCPD</code> power pins.

First example: if VCCPD3B is connected to 2.5 V, then the VCCIO pins for banks 3B and 4A can be connected to any of the following voltages: 1.2 V, 1.25 V, 1.35 V, 1.5 V, 1.8 V, or 2.5 V.

Second example: if VCCPD3B is connected to 3.0 V, then the VCCIO pins for banks 3B and 4A must also be connected to 3.0 V.

V_{REF} Pin Restriction

You cannot assign shared VREF pins as LVDS or external memory interface pins.

SSTL, HSTL, and HSUL I/O standards do not support shared VREF pins.

For example, if a particular B1p or B1n pin is a shared VREF pin, the corresponding B1p/B1n pin pair do not have LVDS transmitter support.

Shared VREF pins will have reduced performance when used as normal I/Os. You must perform SI analysis using your board design to determine the F_{MAX} for your system.

3.3-V I/O Interface

To ensure device reliability and proper operation when you use the Cyclone V device for 3.3-V I/O interfacing, do not violate the absolute maximum ratings of the device.

For a transmitter, use slow slew-rate and series termination to limit the overshoot and undershoot at the I/O pins.

For a receiver, use the on-chip clamp diode to limit the overshoot and undershoot voltage at the I/O pins.

- For more information about absolute maximum rating and maximum allowed overshoot during transitions, refer to the Cyclone V Device Datasheet.
- Altera recommends that you perform IBIS or SPICE simulations to make sure the overshoot and undershoot voltages are within the specifications.

LVDS Channels

For **LVDS** applications, you must use the phase-locked loops (PLLs) in integer PLL mode.

Differential Pin Placement

When you use **LVDS** channels, adhere to the guidelines in the following sections.

The Quartus[®] II compiler automatically checks the design and issues an error message if the guidelines are not followed to ensure proper high-speed operation.

For more information about the Cyclone V device high-speed differential I/O interfaces, refer to "High-Speed Differential I/O Interfaces" on page 5–36.

LVDS Channel Driving Distance

Each PLL can drive all the LVDS channels in the entire quadrant.

Using Corner and Center PLLs

You can use a corner PLL to drive all transmitter channels and a center PLL to drive all **LVDS** receiver channels in the same I/O bank.

A corner PLL and a center PLL can drive duplex channels in the same I/O quadrant if the channels that are driven by each PLL are not interleaved.

You do not require separation between the group of channels that are driven by the corner and center, left and right PLLs.

Figure 5–1 shows two different PLLs driving a transmitter channel and a receiver channel in the same **LVDS** module.



Figure 5–1. Corner and Center PLLs Driving LVDS Differential I/Os in the Same Quadrant

Figure 5–2. shows invalid placement of the LVDS I/Os.





I/O Banks

The number of Cyclone V I/O banks in a particular device depends on the device density.

Each I/O bank can simultaneously support multiple I/O standards.

Figure 5–3 shows the I/O banks in Cyclone V E devices.

Figure 5–3. I/O Banks for Cyclone V E Devices (1)



Note to Figure 5–3:

(1) This is a top view of the silicon die that corresponds to a reverse view of the device package.

Figure 5-4 shows the I/O banks in Cyclone V GX and GT devices.

Figure 5–4. I/O Banks for Cyclone V GX and GT Devices (1)



Note to Figure 5-4:

(1) This is a top view of the silicon die that corresponds to a reverse view of the device package.

Figure 5–5 shows the I/O banks in Cyclone V SE devices.

Figure 5–5. I/O Banks for Cyclone V SE Devices (1)



Note to Figure 5-5:

(1) This is a top view of the silicon die that corresponds to a reverse view of the device package.

Figure 5–6 shows the I/O banks in Cyclone V SX and ST devices.

Figure 5–6. I/O Banks for Cyclone V SX and ST Devices (1)



Note to Figure 5-6:

(1) This is a top view of the silicon die that corresponds to a reverse view of the device package.

Modular I/O Banks

The I/O pins in Cyclone V devices are arranged in groups called modular I/O banks. Table 5–2 list the modular I/O banks for Cyclone V E devices.

Member	Deekere				FPG	A I/O B	ank				Total
Code	Раскаде	2A	3A	3B	4A	5A	5B	6A	7A	8A	Iotai
	F256	16	16	16	16	16	16	_	16	16	128
۸0	U324	32	16	16	32	16	16		32	16	176
A2	U484	16	16	32	48	16	16	_	48	32	224
	F484	16	16	32	48	16	16	_	48	32	224
	F256	16	16	16	16	16	16	_	16	16	128
Δ.4	U324	32	16	16	32	16	16	_	32	16	176
A4	U484	16	16	32	48	16	16	_	48	32	224
	F484	16	16	32	48	16	16	_	48	32	224
۸5	U484	_	16	32	48	16	32	_	48	32	224
AJ	F484	_	16	32	48	16	16	_	80	32	240
	U484	_	16	32	48	16	48	_	48	32	240
۸7	F484	_	16	32	48	16	16	_	80	32	240
Α <i>ι</i>	F672	_	16	32	80	16	64	16	80	32	336
	F896	_	32	48	80	32	48	80	80	80	480
	F484	_	16	32	48	16	16	_	64	32	224
A9	F672		16	32	80	16	32	48	80	32	336
	F896	_	32	48	80	32	48	80	80	80	480

Table 5–2. Modular I/O Banks for Cyclone V E Devices — *Preliminary*

Table 5–3 list the modular I/O banks for Cyclone V GX devices.

Table 5–3. Modular I/O Banks for Cyclone V GX Devices (Part 1 of 2)—Preliminary

Member	Deekere				FPGA I/	0 Bank				Total
Code	Раскаде	3A	3B	4A	5A	5B	6A	7A	8A	Iotai
	U324	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD
C3	U484	16	32	48	16	16	_	48	32	208
	F484	16	32	48	16	16	_	48	32	208
	U484	16	32	48	16	32	_	48	32	224
C4	F484	16	32	48	16	16	_	80	32	240
	F672	16	32	80	16	64	16	80	32	336
	U484	16	32	48	16	32	_	48	32	224
C5	F484	16	32	48	16	16	_	80	32	240
	F672	16	32	80	16	64	16	80	32	336

Member	Dookono			Total						
Code	гаскауе	3A	3B	4A	5A	5B	6A	7A	8A	IULAI
	U484	16	32	48	16	48		48	32	240
07	F484	16	32	48	16	16	_	80	32	240
07	F672	16	32	80	16	64	16	80	32	336
	F896	32	48	80	32	48	80	80	80	480
	F484	16	32	48	16	16	_	64	32	224
CO	F672	16	32	80	16	32	48	80	32	336
09	F896	32	48	80	32	48	80	80	80	480
	F1152	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD

Table 5-3. Modular I/O Banks for Cyclone V GX Devices (Part 2 of 2)-Preliminary

Table 5-4 list the modular I/O banks for Cyclone V GT devices.

FPGA I/O Bank Member Package Total Code 3A 3B 4A 5A 5B 6A 7A 8A U484 _____ F484 D5 ____ F672 U484 ____ F484 ____ D7 F672 F896 F484 ___ F672 D9 F896 F1152 TBD TBD TBD TBD TBD TBD TBD TBD TBD

 Table 5-4. Modular I/O Banks for Cyclone V GT Devices — Preliminary

Table 5–5 list the modular I/O banks for Cyclone V SE devices.

Table 5–5. Modular I/O Banks for Cyclone V SE Devices (Part 1 of 2)—*Preliminary*

Member	Package		FPG/	A I/O	Bank	X	HPS I/O I	Row Bank	HP	S Col Ba	lumn nk	I/O	FPGA I/O Bank	Total
Cone	_	3A	3B	4 A	5A	5B	6A	6B	7A	7B	7C	7D	8A	
٨٥	U484	16	6	22	16	-	52	23	19	21	8	14	6	203
AZ.	U672	16	32	68	16	—	56	44	19	22	12	14	13	312
Δ.4	U484	16	6	22	16	—	52	23	19	21	8	14	6	203
A4	U672	16	32	68	16	—	56	44	19	22	12	14	13	312
	U484	16	6	22	16	-	52	23	19	21	8	14	6	203
A5	U672	16	32	68	16	—	56	44	19	22	12	14	13	312
	F896	32	48	80	32	16	56	44	19	22	12	14	80	455

Member	Package		FPG/	A I/O	Bank	[HPS I/O E	Row Bank	HP	S Col Ba	lumn nk	I/O	FPGA I/O Bank	Total
UUUG		3A	3B	4A	5A	5B	6A	6B	7A	7B	7C	7D	8A	
	U484	16	6	22	16	—	52	23	19	21	8	14	6	203
A6	U672	16	32	68	16	—	56	44	19	22	12	14	13	312
	F896	32	48	80	32	16	56	44	19	22	12	14	80	455

Table 5–5. Modular I/O Banks for Cyclone V SE Devices (Part 2 of 2)—*Preliminary*

Table 5–6 list the modular I/O banks for Cyclone V SX devices.

Table 5–6. Modular I/O Banks for Cyclone V SX Devices — *Preliminary*

Member	Package		FPG/	A I/O	Bank	(HPS I/O I	Row Bank	HP	S Col Ba	lumn Ink	I/O	FPGA I/O Bank	Total
Cone	_	3A	3B	4 A	5A	5B	6A	6B	7A	7B	7C	7D	8A	
C2	U672	16	32	68	16	—	56	44	19	22	12	14	13	312
C4	U672	16	32	68	16		56	44	19	22	12	14	13	312
05	U672	16	32	68	16		56	44	19	22	12	14	13	312
05	F896	32	48	80	32	16	56	44	19	22	12	14	80	455
60	U672	16	32	68	16	—	56	44	19	22	12	14	13	312
00	F896	32	48	80	32	16	56	44	19	22	12	14	80	455

Table 5–7 list the modular I/O banks for Cyclone V ST devices.

Table 5–7.	Modular I	/O Banks for	Cyclone V	ST Devices -	-Preliminary

Member	Package		FPG/	A I/O	Bank	I	HPS I/O E	Row Bank	HP	S Col Ba	lumn nk	I/O	FPGA I/O Bank	Total
GOUE		3A	3B	4A	5A	5B	6A	6B	7A	7B	7C	7D	8A	
D5	F896	32	48	80	32	16	56	44	19	22	12	14	80	455
D6	F896	32	48	80	32	16	56	44	19	22	12	14	80	455

IOE Features

The IOEs in Cyclone V devices contain a bidirectional I/O buffer and I/O registers to support a complete embedded bidirectional single data rate (SDR) or double data rate (DDR) transfer.

The IOEs are located in I/O blocks around the periphery of the Cyclone V device.

Figure 5–7 shows the Cyclone V IOE structure.

Figure 5–7. IOE Structure for Cyclone V Devices (1), (2)



Notes to Figure 5-7:

- (1) The D3 0 and D3 1 delays have the same available settings in the Quartus II software.
- (2) One dynamic OCT control is available for each DQ/DQS group.

Current Strength

You can use the programmable current strength to mitigate the effects of high signal attenuation that is caused by a long transmission line or a legacy backplane.

The output buffer for each Cyclone V device I/O pin has a programmable current strength control for the following I/O standards.

Table 5–8 lists the programmable current strength settings for Cyclone V devices.

I/O Standard	I_{OH} / I_{OL} Current Strength Setting (mA) ⁽¹⁾
3.3-V LVTTL ⁽²⁾	16 ⁽³⁾ , 8 , 4
3.3-V LVCMOS ⁽²⁾	2
3.0-V LVTTL ⁽²⁾	16, 12 , 8, 4
3.0-V LVCMOS ⁽²⁾	16, 12 , 8, 4
2.5-V LVCMOS ⁽²⁾	16, 12 , 8, 4
1.8-V LVCMOS ⁽²⁾	12 , 10, 8, 6, 4, 2
1.5-V LVCMOS ⁽²⁾	12 , 10, 8, 6, 4, 2
1.2-V LVCMOS	8 , 6, 4, 2
SSTL-2 Class I	12, 10, 8
SSTL-2 Class II	16
SSTL-18 Class I ⁽²⁾	12, 10, 8 , 6, 4
SSTL-18 Class II ⁽²⁾	16
SSTL-15 Class I ⁽²⁾	12, 10, 8 , 6, 4
SSTL-15 Class II ⁽²⁾	16
1.8-V HSTL Class I	12, 10, 8 , 6, 4
1.8-V HSTL Class II	16
1.5-V HSTL Class I ⁽²⁾	12, 10, 8 , 6, 4
1.5-V HSTL Class II ⁽²⁾	16
1.2-V HSTL Class I	12, 10, 8 , 6, 4
1.2-V HSTL Class II	16

 Table 5–8. Programmable Current Strength Settings — Preliminary

Notes to Table 5-8:

(1) The default current strength setting in the Quartus II software is the current strength shown in bold.

(2) Supported in HPS.

(3) Not Supported in HPS.

Altera recommends that you perform IBIS or SPICE simulations to determine the best current strength setting for your specific application.

MultiVolt I/O Interface

The MultiVolt I/O interface feature that allows Cyclone V devices in all packages to interface with systems of different supply voltages.

Table 5–9 lists Cyclone V MultiVolt I/O support.

Table 5–9. MultiVolt I/O Support in Cyclone V Devices (1), (2)

V _{CCIO}				Input \$	Signal (V)					0	utput S	ignal (V)		
(V)	1.2	1.25	1.35	1.5	1.8	2.5	3.0	3.3	1.2	1.25	1.35	1.5	1.8	2.5	3.0	3.3
1.2	Y	—		_	_	_	—		Y	—	_	_	_	_	_	
1.25	_	Y		_	—	—	—	_	_	Y	_	_	_	_	_	—
1.35	_		Y	_	—	—	—	_	_		Y	_	_	_	_	—
1.5			_	Y	Y	_	_					Y				_
1.8	_			Y	Y	—	—	_	_		_	_	Y	_	_	—
2.5	_			_	—	Y	Υ <i>(3)</i>	γ <i>(3)</i>	_		_	_	_	Y	_	—
3.0			_		_	Y	Υ <i>(3)</i>	Υ <i>(3)</i>							Y	_
3.3		—	—		—	Y	Υ <i>(3)</i>	γ <i>(3)</i>								Y

Notes to Table 5-9:

(1) The pin current may be slightly higher than the default value. Verify that the V_{0L} maximum and V_{0H} minimum voltages of the driving device do not violate the applicable V_{1L} maximum and V_{1H} minimum voltage specifications of the Cyclone V device.

(2) For $V_{CCIO} = 1.2$, 1.25, 1.35, 1.5, 1.8, and 2.5 V, $V_{CCPD} = 2.5$ V. For $V_{CCIO} = 3.0$ V, $V_{CCPD} = 3.0$ V. For $V_{CCIO} = 3.3$ V, $V_{CCPD} = 3.3$ V.

(3) Altera recommends using the on-chip clamp diode on the I/O pins when the input signal is 3.0 V or 3.3 V.

Programmable IOE Features

The Cyclone V I/O supports programmable features, as listed in Table 5–10.

Feature	Setting	Condition
Slew Rate Control	0 = Slow, 1 = Fast (default)	Disabled when you use the R _S OCT feature.
I/O Delay	(1)	—
Open-Drain Output	On, Off (default)	—
Bus-Hold	On, Off (default)	Disabled when you use the weak pull-up resistor feature.
Weak Pull-up Resistor	On, Off (default)	Disabled when you use the bus-hold feature.
Pre-Emphasis	0 = Disabled, 1 = Enabled (default)	For LVDS I/O standard only. Not supported for differential HSTL and SSTL I/O standards.
Differential Output Voltage	0 = low, $1 = $ medium (default), 2 = high	—
On-Chip Clamp Diode ⁽²⁾	On, Off (default)	Recommended to turn on for 3.3-V I/O standards

Table 5–10. Supported I/O Features and Settings ⁽¹⁾

Notes to Table 5-10:

(1) For information about the programmable IOE features, refer to the Cyclone V Device Datasheet.

(2) The PCI on-chip clamp diode is available on all general purpose I/O (GPIO) pins in all Cyclone V device variants.

Slew-Rate Control

The programmable output slew-rate control in the output buffer of each regular- and dual-function I/O pin allows you to configure the following:

- Fast slew rate—provides high-speed transitions for high-performance systems.
- Slow slew rate—reduces system noise and crosstalk but adds a nominal delay to the rising and falling edges.

You can specify the slew rate on a pin-by-pin basis because each I/O pin contains a slew-rate control.

Altera recommends that you perform IBIS or SPICE simulations to determine the best slew rate setting for your specific application.

I/O Delay

The following sections describe the programmable IOE delay and the programmable output buffer delay.

Programmable IOE Delay

You can activate the programmable delays to ensure zero hold times, minimize setup times, or increase clock-to-output times.

This feature helps read and write timing margins because it minimizes the uncertainties between signals in the bus.

Each pin can have a different input delay from pin-to-input register or a delay from output register-to-output pin values to ensure that the signals within a bus have the same delay going into or out of the device.

For more information about programmable IOE delay specifications, refer to the *Cyclone V Device Datasheet*.

Programmable Output Buffer Delay

The device supports delay chains built inside the single-ended output buffer.

There are four levels of output buffer delay settings. By default, there is no delay.

The following actions allow you to independently control the rising and falling edge delays of the output buffer:

- Adjust the output-buffer duty cycle
- Compensate channel-to-channel skew
- Reduce simultaneous switching output (SSO) noise by deliberately introducing channel-to-channel skew
- Improve high-speed memory-interface timing margins

For more information about programmable output buffer delay specifications, refer to the *Cyclone V Device Datasheet*.

Open-Drain Output

The optional open-drain output for each I/O pin is equivalent to an open collector output.

When configured as an open drain, the logic value of the output is either high-Z or logic low.

Use an external resistor to pull the signal to a logic high.

Bus-Hold

Each I/O pin provides an optional bus-hold feature that is active only after configuration. When the device enters user mode, the bus-hold circuit captures the value that is present on the pin by the end of the configuration.

The bus-hold circuitry uses a resistor with a nominal resistance (R_{BH}), approximately 7 k Ω to weakly pull the signal level to the last-driven state of the pin. The bus-hold circuitry holds this pin state until the next input signal is present. Because of this, you do not require an external pull-up or pull-down resistor to hold a signal level when the bus is tri-stated.

For each I/O pin, you can individually specify that the bus-hold circuitry pulls non-driven pins away from the input threshold voltage—where noise can cause unintended high-frequency switching. To prevent over-driving signals, the bus-hold circuitry drives the voltage level of the I/O pin lower than the V_{CCIO} level.

If you enable the bus-hold feature, you cannot use the programmable pull-up option. To configure the I/O pin for differential signals, disable the bus-hold feature.

Pull-Up Resistor

The pull-up resistor weakly holds the I/O to the V_{CCIO} level.

The Cyclone V device supports programmable weak pull-up resistors only on user I/O pins but not on dedicated configuration pins, JTAG pins, or dedicated clock pins.

Each I/O pin provides an optional programmable pull-up resistor during user mode.

If you enable this option, you cannot use the bus-hold feature.

Pre-Emphasis

Pre-emphasis boosts the output current momentarily.

The overshoot introduced by the extra current happens only during a change of state switching to increase the output slew rate and does not ring, unlike the overshoot caused by signal reflection.

The V_{OD} setting and the output impedance of the driver set the output current limit of a high-speed transmission signal. At a high frequency, the slew rate may not be fast enough to reach the full V_{OD} level before the next edge, producing pattern-dependent jitter.

The amount of pre-emphasis required depends on the attenuation of the high-frequency component along the transmission line.

For more information, refer to "Programmable Pre-Emphasis" on page 5-48.

Differential Output Voltage

The Cyclone V LVDS transmitters support programmable V_{OD}.

The programmable $V_{\rm OD}$ settings allow you to adjust the output eye opening to optimize the trace length and power consumption. A higher $V_{\rm OD}$ swing improves voltage margins at the receiver end, and a smaller $V_{\rm OD}$ swing reduces power consumption.

For more information, refer to "Programmable V_{OD} " on page 5–47.

For the weak pull-up resistor value, refer to the *Cyclone V Device Datasheet.*

OCT Schemes

Dynamic R_S and R_T OCT provides I/O impedance matching and termination capabilities. OCT maintains signal quality, saves board space, and reduces external component costs.

Cyclone V devices support OCT in all I/O banks.

Table 5–11 lists the OCT schemes supported in Cyclone V devices.

Table 5–11. OCT Schemes in Cyclone V

Direction	OCT Schemes	
Outout	OCT R _S with calibration ⁽¹⁾	
Output	OCT R _S without calibration ⁽¹⁾	
Input	OCT R_T with calibration ⁽¹⁾	
input	OCT R _D (LVDS I/O standard only)	
Bidirectional	Dynamic OCT R_S and OCT R_T	

Note to Table 5-11:

(1) For information about OCT support for the selectable I/O standards, refer to Table 5-12.

OCT Calibration Block

You can calibrate the OCT using any of the available three OCT calibration blocks for each device. Each calibration block contains one RZQ pin.

Figure 5–8 shows the location of I/O banks with OCT calibration blocks and RZQ pins.

Figure 5–8. OCT Calibration Block and RZQ Pin Location ⁽¹⁾—Preliminary



Note to Figure 5-8:

(1) This is a top view of the silicon die that corresponds to a reverse view of the device package. This figure illustrates the highest density for Cyclone V devices.

You can use R_S and R_T OCT in the same I/O bank for different I/O standards if the R_S and R_T OCT use the same V_{CCIO} supply voltage. You cannot configure the R_S OCT and the programmable current strength for the same I/O buffer.

Connect the RZQ pin to the GND pin through a resistor with the specified value. The RZQ pin shares the same V_{CCIO} supply voltage with the I/O bank where the pin is located.

Cyclone V devices support calibrated R_S and calibrated R_T on all I/O pins except for dedicated configuration pins.

Table 5–12 lists the input and output termination settings for calibrated and uncalibrated OCT on different I/O standards.

		Output Termination			Input Termination	
I/O standards	Uncalibrated OCT Setting	Calibrated OCT Setting		Calibrated OCT Setting		
	R s (Ω)	R _S (Ω) ⁽¹⁾	RZQ (Ω)	R_T (Ω) ⁽¹⁾	RZQ (Ω)	
3.3-V LVTTL/3.3-V LVCMOS	—	—	_			
3.0-V LVVTL/3.0-V LVCMOS	25/50	25/50	100			
2.5-V LVCMOS	25/50	25/50	100	—	_	
1.8-V LVCMOS	25/50	25/50	100			
1.5-V LVCMOS	25/50	25/50	100			
1.2-V LVCMOS	25/50	25/50	100	—	_	
SSTL-2 Class I	50	50	100	50	100	
SSTL-2 Class II	25	25	100	50	100	
SSTL-18 Class I	50	50	100	50	100	
SSTL-18 Class II	25	25	100	50	100	
SSTL-15 Class I	50	50	100	50	100	
SSTL-15 Class II	25	25	100	50	100	
1.8-V HSTL Class I	50	50	100	50	100	
1.8-V HSTL Class II	25	25	100	50	100	
1.5-V HSTL Class I	50	50	100	50	100	
1.5-V HSTL Class II	25	25	100	50	100	
1.2-V HSTL Class I	50	50	100	50	100	
1.2-V HSTL Class II	25	25	100	50	100	
SSTI -12		25/50	100	20, 30, 40, 60,	240	
331L-13		34/40	240	120	240	
SSTL-135	_	34/40	240	20, 30, 40, 60, 120	240	
SSTL-125	—	34/40	240	20, 30, 40, 60, 120	240	
HSUL-12	_	34/40/48/60/80	240			
Differential SSTL-2 Class I	50	50	100	50	100	
Differential SSTL-2 Class II	25	25	100	50	100	
Differential SSTL-18 Class I	50	50	100	50	100	
Differential SSTL-18 Class II	25	25	100	50	100	
Differential SSTL-15 Class I	50	50	100	50	100	
Differential SSTL-15 Class II	25	25	100	50	100	
Differential 1.8-V HSTL Class I	50	50	100	50	100	
Differential 1.8-V HSTL Class II	25	25	100	50	100	
Differential 1.5-V HSTL Class I	50	50	100	50	100	

	Table 5-12.	Selectable I/O	Standards for Re	and R _T	OCT with a	nd without	Calibration	(Part 1 of	2)
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	Output Termination			Input Termination	
I/O standards	Uncalibrated OCT Setting	Calibrated OCT Setting		Calibrated OCT Setting	
	R_S (Ω)	R_S (Ω) ⁽¹⁾	RZQ (Ω)	R_T (Ω) ⁽¹⁾	RZQ (Ω)
Differential 1.5-V HSTL Class II	25	25	100	50	100
Differential 1.2-V HSTL Class I	50	50	100	50	100
Differential 1.2-V HSTL Class II	25	25	100	50	100
Differential SSTL -15	_	25/50	100	20, 30, 40, 60, 120	240
		34/40	240		240
Differential SSTL-135	_	34/40	240	20, 30, 40, 60, 120	240
Differential SSTL-125	_	34/40	240	20, 30, 40, 60, 120	240
Differential HSUL-12		34/40/48/60/80	240	—	

Table 5–12. Selectable I/O Standards for R_{S} and R_{T} OCT with and without Calibration (Part 2 of 2)

Note to Table 5-12:

(1) The final values for the calibrated R_{S} and R_{T} OCT are pending silicon characterization.

Sharing an OCT Calibration Block on Multiple I/O Banks

An OCT calibration block has the same V_{CCIO} as the I/O bank that contains the block. All I/O banks with the same V_{CCIO} can share one OCT calibration block, even if that particular I/O bank has an OCT calibration block.

 $\rm I/O$ banks that do not have calibration blocks share the calibration blocks in the $\rm I/O$ banks that have calibration blocks.

All I/O banks support OCT calibration with different V_{CCIO} voltage standards, up to the number of available OCT calibration blocks.

You can configure the I/O banks to receive calibration codes from any OCT calibration block with the same V_{CCIO} . If a group of I/O banks has the same V_{CCIO} voltage, you can use one OCT calibration block to calibrate the group of I/O banks placed around the periphery.

For example, Figure 5–9 shows a group of I/O banks that is using the same V_{CCIO} voltage. This figure does not show transceiver calibration blocks.

Figure 5–9. Example of Calibrating Multiple I/O Banks with One Shared OCT Calibration Block ⁽¹⁾—*Preliminary*



Note to Figure 5–9:

(1) This is a top view of the silicon die that corresponds to a reverse view of the device package. This figure illustrates the highest density for Cyclone V devices.

Because banks 5A, and 7A have the same V_{CCIO} as bank 3A, you can calibrate all three I/O banks (3A, 5A, and 7A) with the OCT calibration block (CB3) located in bank 3A.

To enable this calibration, serially shift out the R_S OCT calibration codes from the OCT calibration block in bank 3A to the I/O banks around the periphery.

For more information about the OCT calibration block, refer to the *Dynamic Calibrated On-Chip Termination (ALTOCT) Megafunction User Guide.*

R_S OCT with Calibration

Cyclone V devices support R_S OCT with calibration in all banks.

The R_S OCT calibration circuit compares the total impedance of the I/O buffer to the external reference resistor connected to the RZQ pin and dynamically enables or disables the transistors until they match.

Calibration occurs at the end of device configuration. When the calibration circuit finds the correct impedance, the circuit powers down and stops changing the characteristics of the drivers.

Figure 5–10 shows the R_S as the intrinsic impedance of the output transistors.



Figure 5–10. R_s OCT with Calibration

R_s OCT Without Calibration

Cyclone V devices support $R_{\rm S}$ OCT for single-ended and voltage-referenced I/O standards.

Driver-impedance matching provides the I/O driver with controlled output impedance that closely matches the impedance of the transmission line. As a result, you can significantly reduce signal reflections on PCB traces.

When you select matching impedance, current strength is no longer selectable.

Figure 5–11 shows the R_S as the intrinsic impedance of the output transistors.

Figure 5–11. R_s OCT Without Calibration



$R_{T}\ OCT$ with Calibration

Cyclone V devices support R_T OCT with calibration in all banks.

The $R_T OCT$ calibration circuit compares the total impedance of the I/O buffer to the external resistor connected to the RZQ pin. The circuit dynamically enables or disables the transistors until the total impedance of the I/O buffer matches the external resistor.

Calibration occurs at the end of the device configuration. When the calibration circuit finds the correct impedance, the circuit powers down and stops changing the characteristics of the drivers.

Figure 5–12 shows R_T OCT with calibration.



Figure 5–12. R_T OCT with Calibration

 R_T OCT with calibration is available only for configuration of input and bidirectional pins. Output pin configurations do not support R_T OCT with calibration. When you use R_T OCT, the V_{CCIO} of the bank must match the I/O standard of the pin where you enable the R_T OCT.

Dynamic OCT

Dynamic OCT is useful for terminating a high-performance bidirectional path by optimizing the signal integrity depending on the direction of the data.

Dynamic R_T OCT or R_S OCT is enabled or disabled based on whether the bidirectional I/O acts as a receiver or driver, as listed in Table 5–13.

Table 5-13. Dynamic OCT Based on Bidirectional I/O

Dynamic OCT	Bidirectional I/O	State
Dynamic R_ OCT	Acts as a receiver	Enabled
	Acts as a driver	Disabled
Dunamic P. OCT	Acts as a receiver	Disabled
Dynamic n _S OCT	Acts as a driver	Enabled

Figure 5–13 shows the dynamic R_T OCT supported in the device.



Figure 5–13. Dynamic R_T OCT in Cyclone V Devices

Altera recommends that you use dynamic OCT for the DDR3 memory interface if you use the **SSTL-15**, **SSTL-135**, and **SSTL-125** I/O standards. These I/O standards save board space by reducing the number of external termination resistors used.

LVDS Input R_D OCT

Cyclone V devices support R_D OCT in all I/O banks.

You can use R_D OCT when you set the V_{CCIO} and V_{CCPD} to 2.5 V.

Cyclone V devices support OCT for differential **LVDS** input buffers with a nominal resistance value of 100 Ω as shown in Figure 5–14.

Figure 5–14. Differential Input OCT



I/O Standards Termination Schemes

The following sections describe the different termination schemes for the I/O standards supported in Cyclone V devices.

Table 5–14 lists the external termination schemes for the different I/O standards.

 Table 5–14.
 I/O Standards External Termination Scheme (Part 1 of 2)

I/O standards	External Termination Scheme			
3.3-V LVTTL/3.3-V LVCMOS				
3.0-V LVVTL/3.0-V LVCMOS				
2.5-V LVCMOS				
1.8-V LVCMOS	No external termination required			
1.5-V LVCMOS	No external termination required			
1.2-V LVCMOS				
3.0-V PCI				
3.0-V PCI-X				
SSTL-2 Class I				
SSTL-2 Class II				
SSTL-18 Class I	Single-Ended SSTI 1/0 Standard Termination			
SSTL-18 Class II				
SSTL-15 Class I				
SSTL-15 Class II				
1.8-V HSTL Class I				
1.8-V HSTL Class II				
1.5-V HSTL Class I	Single-Ended HSTI 1/0 Standard Termination			
1.5-V HSTL Class II				
1.2-V HSTL Class I				
1.2-V HSTL Class II				
SSTL-15 ⁽¹⁾				
SSTL-135 ⁽¹⁾	No external termination required			
SSTL-125 ⁽¹⁾				
HSUL-12				
Differential SSTL-2 Class I				
Differential SSTL-2 Class II				
Differential SSTL-18 Class I	Differential SSTL I/O Standard Termination			
Differential SSTL-18 Class II				
Differential SSTL-15 Class I				
Differential SSTL-15 Class II				

I/O standards	External Termination Scheme			
Differential 1.8-V HSTL Class I				
Differential 1.8-V HSTL Class II				
Differential 1.5-V HSTL Class I	Differential UST 1/0 Standard Termination			
Differential 1.5-V HSTL Class II				
Differential 1.2-V HSTL Class I				
Differential 1.2-V HSTL Class II				
Differential SSTL-15 (1)				
Differential SSTL-135 (1)	No external termination required			
Differential SSTL-125 (1)				
Differential HSUL-12				
LVDS	LVDS I/O Standard Termination			
RSDS ⁽²⁾	PSDS/mini-LVDS 1/0 Standard Termination			
Mini-LVDS ⁽³⁾				
LVPECL	Differential LVPECL I/O Standard Termination			
SLVS	SLVS I/O Standard Termination			

Table 5–14. I/O Standards External Termination Scheme (Part 2 of 2)

Notes to Table 5-14:

(1) Altera recommends using dynamic OCT with these I/O standards to save board space and cost by reducing the number of external termination resistors.

(2) Cyclone V devices support the true **RSDS** output standard with data rates of up to 230 Mbps using true **LVDS** output buffer types on all I/O banks.

(3) Cyclone V devices support the true mini-LVDS output standard with data rates of up to 340 Mbps using true LVDS output buffer types on all I/O banks.

Single-Ended I/O Standard Termination

Voltage-referenced I/O standards require an input V_{REF} and a termination voltage (V_{TT}). The reference voltage of the receiving device tracks the termination voltage of the transmitting device.

The supported I/O standards such as **SSTL-15**, **SSTL-135**, **SSTL-125**, and **SSTL-12** typically do not require external board termination.

Altera recommends using dynamic OCT with these I/O standards to save board space and cost. Dynamic OCT reduces the number of external termination resistors used.

Figure 5–15 shows the details of SSTL I/O termination on Cyclone V devices.

Figure 5–15. SSTL I/O Standard Termination





Figure 5–16 shows the details of HSTL I/O termination on Cyclone V devices.



You cannot use R_s and R_T OCT simultaneously. For more information, refer to "Dynamic OCT" on page 5–25.

Differential I/O Standard Termination

The I/O pins are organized in pairs to support differential I/O standards. Each I/O pin pair can support differential input and output buffers.

The supported I/O standards such as **differential SSTL-12**, **differential SSTL-15**, **differential SSTL-125**, and **differential SSTL-135** typically do not require external board termination.

Altera recommends using these I/O standards with dynamic OCT schemes to save board space and costs by reducing the number of external termination resistors used.

Differential HSTL, **SSTL**, and **HSUL** inputs use **LVDS** differential input buffers. However, R_D support is only available if the I/O standard is **LVDS**. **Differential HSTL**, **SSTL**, and **HSUL** outputs are not true differential outputs. They use two single-ended outputs with the second output programmed as inverted.

Figure 5–17 shows the details of **Differential SSTL** I/O termination on Cyclone V devices.



Figure 5–17. Differential SSTL I/O Standard Termination

Figure 5–18 shows the details of **Differential HSTL** I/O standard termination on Cyclone V devices.

Figure 5–18. Differential HSTL I/O Standard Termination



LVDS, RSDS, and Mini-LVDS I/O Standard Termination

All I/O banks have dedicated circuitry to support the true **LVDS**, **RSDS**, and **mini-LVDS** I/O standards by using true **LVDS** output buffers without resistor networks.

Figure 5–19 shows the **LVDS** I/O standard termination. The on-chip differential resistor is available in all I/O banks.





LVPECL I/O Standard Termination

Cyclone V devices support the **LVPECL** I/O standard on input clock pins only. **LVPECL** output operation is not supported. Use **LVDS** input buffers to support the **LVPECL** input operation.

Use AC coupling when the **LVPECL** common-mode voltage of the output buffer does not match the **LVPECL** input common-mode voltage.

Figure 5–20 shows the AC-coupled termination scheme.

Figure 5–20. LVPECL AC-Coupled Termination (1)



Note to Figure 5-20:

(1) The LVPECL AC/DC-coupled termination is applicable only when you use an Altera® FPGA transmitter.

Support for DC-coupled **LVPECL** is available if the **LVPECL** output common mode voltage is within the Cyclone V **LVPECL** input buffer specification, as shown in Figure 5–21.





Note to Figure 5-21:

(1) The LVPECL AC/DC-coupled termination is applicable only when you use an Altera FPGA transmitter.

Emulated LVDS, RSDS, and Mini-LVDS I/O Standard Termination

The I/O banks also support emulated LVDS, RSDS, and mini-LVDS I/O standards.

Emulated LVDS, RSDS and mini-LVDS output buffers use two single-ended output buffers with either an external single resistor for data rates up to 200 Mbps or an external three-resistor network for data rates up to 1.1 Gbps, and can be tri-stated.

The output buffers are available in all I/O banks, as shown in Figure 5–22.



Figure 5–22. Emulated LVDS, RSDS, or Mini-LVDS I/O Standard Termination (1)

Note to Figure 5-22:

(1) The R_1 , R_S , and R_P values are pending characterization.

To meet the **RSDS** or **mini-LVDS** specifications, you require a resistor network to attenuate the output-voltage swing.

You can modify the three-resistor network values to reduce power or improve the noise margin. Choose resistor values that satisfy Equation 5–1.

$$\frac{R_{S} \times \frac{R_{P}}{2}}{R_{S} + \frac{R_{P}}{2}} = 50 \ \Omega$$

- Altera recommends that you perform additional simulations with IBIS or SPICE models to validate that the custom resistor values meet the **RSDS** or **mini-LVDS** I/O standard requirements.
- ***** For more information about the **RSDS** I/O standard, refer to the *RSDS Specification* document available on the National Semiconductor web site (www.national.com).

5–36

High-Speed Differential I/O Interfaces

This section describes the interface signals of the transmitter and receiver data path.

Figure 5–23 shows a transmitter and receiver block diagram for the **LVDS** SERDES circuitry.

Figure 5–23. LVDS SERDES (1), (2)



Notes to Figure 5-23:

- (1) This diagram shows a shared PLL between the transmitter and receiver. If the transmitter and receiver do not share the same PLL, you require two fractional PLLs.
- (2) In single data rate (SDR) and double data rate (DDR) modes, the data width are 1 and 2 bits, respectively.
- (3) The tx_in and rx_out ports have a maximum data width of 10 bits.

• For more information about the **LVDS** transmitter and receiver port list and settings using ALTLVDS megafunction, refer to the *LVDS SERDES Transmitter/Receiver* (*ALTLVDS_RX and ALTLVDS_TX*) *Megafunction User Guide*.

High-Speed Differential I/O Locations

The dedicated SERDES circuitry that supports high-speed differential I/Os is located in the top and bottom banks of the Cyclone V devices.

Figure 5–24 shows the high-speed I/O locations in Cyclone V E A2 and A4 devices.





Figure 5–25 shows the high-speed I/O locations in Cyclone V GX C3 devices.



Figure 5–25. High-Speed Differential I/O Location for Cyclone V GX C3 Devices

Transceiver Block

Figure 5–26 shows the high-speed I/O locations in Cyclone V C4, C5, C7, and C9 devices, and Cyclone V GT D5, D7, and D9 devices.





Figure 5–27 shows the high-speed I/O locations in Cyclone V SX C2, C4, C5, and C6 devices, and Cyclone V ST D5 and D6 devices.





Figure 5–27 shows the high-speed I/O locations in Cyclone V SE A2, A4, A5, and A6 devices.





LVDS Channels and Dedicated Circuitry

The Cyclone V device family supports **LVDS** on all I/O banks. Row and column I/Os support true **LVDS** input buffers with R_D OCT and true **LVDS** output buffers. Dedicated SERDES is available for top and bottom banks only

Alternatively, you can configure the unutilized true **LVDS** input buffers as emulated **LVDS** output buffers (eTX) that use two single-ended output buffers with an external resistor network to support **LVDS**, **mini-LVDS**, and **RSDS** standards.

Cyclone V devices offer single-ended I/O reference clock support for the **LVDS** SERDES.

Emulated differential output buffers support tri-state capability. True **LVDS** output buffers cannot be tri-stated.

Table 5–15 lists the number of true LVDS channels supported in Cyclone V devices.

Table 5–15. LVDS Channels Supported in Cyclone V Devices (Part 1 of 4)

Variant	Member Code	Package	Side	тх	RX
	A2	256-pin FineLine BGA	Top/Bottom	TBD	TBD
	A4	484-pin Ultra FineLine BGA 484-pin FineLine BGA	Left/Right	TBD	TBD
			Тор	8	8
		324-pin FineLine BGA	Right	12	12
			Bottom	12	12
		484-pin Ultra FineLine BGA 484-pin FineLine BGA	Тор	20	20
	A5		Right	16	16
			Bottom	20	20
		672-pin FineLine BGA	Тор	32	32
			Right	28	28
			Bottom	32	32
Cyclone V E		484-pin Ultra FineLine BGA	Тор	20	20
			Right	16	16
			Bottom	24	24
		484-pin FineLine BGA	Тор	28	28
			Right	8	8
	Δ7		Bottom	24	24
	AI.		Тор	28	28
		672-pin FineLine BGA	Right	24	24
			Bottom	32	32
			Тор	40	40
		896-pin FineLine BGA	Right	40	40
			Bottom	40	40

Variant	Member Code	Package	Side	тх	RX
			Тор	28	28
		672-pin FineLine BGA	Right	24	24
			Bottom	32	32
			Тор	36	36
Cyclone V E	A9	896-pin FineLine BGA	Right	40	40
			Bottom	36	36
			Тор	48	48
		1152-pin FineLine BGA	Right	48	48
			Bottom	48	48
		256-pin FineLine BGA	Тор	4	4
	С3		Right	8	8
			Bottom	12	12
		324-pin FineLine BGA	Тор	8	8
			Right	12	12
			Bottom	12	12
		484-pin Ultra FineLine BGA 484-pin FineLine BGA	Тор	20	20
Quelene M OX			Right	16	16
			Bottom	20	20
Cyclone v GA		324-pin FineLine BGA	Тор	8	8
			Right	12	12
			Bottom	12	12
			Тор	20	20
	C4 C5	484-pin Ultra FineLine BGA	Right	16	16
			Bottom	20	20
			Тор	32	32
		672-pin FineLine BGA	Right	28	28
			Bottom	32	32

Table 5–15. LVDS Channels Supported in Cyclone V Devices (Part 2 of 4)

Variant	Member Code	Package	Side	тх	RX
			Тор	20	20
		484-pin Ultra FineLine BGA	Right	16	16
			Bottom	24	24
			Тор	28	28
		484-pin FineLine BGA	Right	8	8
	07		Bottom	24	24
	07		Тор	28	28
		672-pin FineLine BGA	Right	24	24
			Bottom	32	32
			Тор	40	40
Cyclone V CV		896-pin FineLine BGA	Right	40	40
Cyclone V GX			Bottom	40	40
		672-pin FineLine BGA	Тор	28	28
			Right	24	24
			Bottom	32	32
			Left	0	0
	0	896-pin FineLine BGA	Тор	36	36
	69		Right	40	40
			Bottom	36	36
		1152-pin FineLine BGA	Тор	48	48
			Right	48	48
			Bottom	48	48
			Тор	8	8
		324-pin FineLine BGA	Right	12	12
			Bottom	12	12
			Тор	20	20
Cyclone V GT	D5	484-pin Ultra FineLine BGA	Right	16	16
			Bottom	20	20
			Тор	32	32
		672-pin FineLine BGA	Right	28	28
			Bottom	32	32

Table 5–15. LVDS Channels Supported in Cyclone V Devices (Part 3 of 4)

Variant	Member Code	Package	Side	тх	RX
			Тор	20	20
		484-pin Ultra FineLine BGA	Right	16	16
			Bottom	24	24
			Тор	28	28
		484-pin FineLine BGA	Right	8	8
	D7		Bottom	24	24
	זט		Тор	28	28
		672-pin FineLine BGA	Right	24	24
			Bottom	32	32
		896-pin FineLine BGA	Тор	40	40
Cyclone V GT			Right	40	40
			Bottom	40	40
		672-pin FineLine BGA	Тор	28	28
			Right	24	24
			Bottom	32	32
		896-pin FineLine BGA	Тор	36	36
	D9		Right	40	40
			Bottom	36	36
		1152-pin FineLine BGA	Тор	48	48
			Right	48	48
			Bottom	48	48

Table 5-15.	LVDS Channels	Supported in	Cyclone V	Devices	(Part 4 of 4)	
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The Cyclone V device has dedicated circuitries for differential transmitter and receiver to transmit or receive high-speed differential signals.

Table 5–16 lists the features of the Cyclone V differential transmitter and receiver dedicated circuitries.

Table 5–16.	Differential	Transmitter and	Receiver	Dedicated	Circuitries in	n Cyclone V
Devices (P	art 1 of 2)					-

Features	Differential Transmitter	Differential Receiver
True differential buffer	LVDS, mini-LVDS, and RSDS	LVDS, SLVS, mini-LVDS, and RSDS
SERDES	Up to 10-bit serializer	Up to 10-bit deserializer
Fractional PLL	Clocks the load and shift registers	Generates different phases of a clock for data synchronizer
Programmable V _{OD}	Static (0, 1, 2)	

Features	Differential Transmitter	Differential Receiver
Programmable pre-emphasis	Boosts output current (0=disable, 1=enable)	_
Data realignment block (Bit-slip)	_	Inserts bit latencies into serial data
Skew Adjustment	—	Manual
On-chip termination (OCT)	_	100 Ω in LVDS and SLVS standards

 Table 5–16. Differential Transmitter and Receiver Dedicated Circuitries in Cyclone V

 Devices (Part 2 of 2)

Fractional PLLs and Cyclone V Clocking

You can use fractional PLLs to reduce the number of oscillators and the clock pins used in the FPGA by synthesizing multiple clock frequencies from a single reference clock source.

The Cyclone V device family supports fractional PLLs on each side of the device. Figure 5–25 on page 5–37 and Figure 5–27 on page 5–38 show the location of the fractional PLLs supported for the high-speed differential I/O receiver and transmitter channels.

The center or corner fractional PLLs can drive the **LVDS** receiver and driver channels. The clock tree network cannot cross over to different I/O regions.

For example, the top left corner fractional PLL cannot cross over to drive the **LVDS** receiver and driver channels on the top right I/O bank.

For more information about fractional PLLs and clocking, refer to the *Clock Networks* and *PLLs in Cyclone V Devices* chapter.

The MegaWizard Plug-In Manager software provides an option for implementing the **LVDS** interface with the external PLL mode. With this mode enabled, you can control the PLL settings, such as dynamically reconfiguring the PLL to support different data rates, dynamic phase shift, and other settings. You also must instantiate the appropriate megafunction to generate the various clocks and load enable signals.

For more information about the external PLL mode, refer to "Generating Clock Signals for LVDS Interface" section in the *LVDS SERDES Transmitter/Receiver (ALTLVDS_RX and ALTLVDS_TX) Megafunction User Guide.*

Differential Transmitter

Figure 5–29 shows a block diagram of the Cyclone V transmitter.

Figure 5–29. Cyclone V Transmitter ^{(1), (2)}



Notes to Figure 5-29:

- (1) In SDR and DDR modes, the data width is 1 and 2 bits, respectively.
- (2) The tx_in port has a maximum data width of 10 bits.

Transmitter Clocking

The fractional PLL generates the parallel clocks (rx_outclock and tx_outclock), the load enable (LVDS_LOAD_EN) signal and the diffioclk signal (the clock running at serial data rate) that clocks the load and shift registers. You can statically set the serialization factor to x4, x5, x6, x7, x8, x9, or x10 using the Quartus II software. The load enable signal is derived from the serialization factor setting.

You can configure any Cyclone V transmitter data channel to generate a source-synchronous transmitter clock output. This flexibility allows the placement of the output clock near the data outputs to simplify board layout and reduce clock-to-data skew.

Different applications often require specific clock-to-data alignments or specific data-rate-to-clock-rate factors. You can specify these settings statically in the Quartus II MegaWizard™ Plug-In Manager:

- The transmitter can output a clock signal at the same rate as the data—with a maximum output clock frequency that each speed grade of the device supports.
- You can also divide the output clock by a factor of 1, 2, 4, 6, 8, or 10, depending on the serialization factor.
- You can set the phase of the clock in relation to the data at 0° or 180° (edge or center aligned). The fractional PLLs provide additional support for other phase shifts in 45° increments.

Figure 5–30 shows the Cyclone V transmitter in clock output mode. In clock output mode, you can use an **LVDS** channel as a clock output channel.



Figure 5–30. Cyclone V Transmitter in Clock Output Mode

Serializer Bypass for DDR and SDR Operations

You can bypass the Cyclone V serializer to support DDR (x2) and SDR (x1) operations to achieve a serialization factor of 2 and 1, respectively. The I/O element (IOE) contains two data output registers that can each operate in either DDR or SDR mode.

Figure 5–31 shows the serializer bypass path.





Notes to Figure 5-31:

- (1) All disabled blocks and signals are grayed out.
- (2) In DDR mode, tx_inclock clocks the IOE register. In SDR mode, data is passed directly through the IOE.
- (3) In SDR and DDR modes, the data width to the IOE is 1 and 2 bits, respectively.

Programmable V_{OD}

You can statically adjust the V_{OD} of the differential signal by changing the V_{OD} settings in the Assignment Editor.

Figure 5–32 shows the V_{OD} of the differential **LVDS** output.

Figure 5–32. Differential V_{0D}



Table 5–17 lists the assignment name for programmable V_{OD} and its possible values in the Quartus II software Assignment Editor.

Table 5–17. Quartus II Software Assignment Editor—Programmable V_{OD}

Field	Assignment
То	tx_out
Assignment name	Programmable Differential Output Voltage (V _{OD})
Allowed values	00 (low), 01 (medium—default), 10 (high)

Programmable Pre-Emphasis

Pre-emphasis increases the amplitude of the high-frequency component of the output signal, and thus helps to compensate for the frequency-dependent attenuation along the transmission line.

Figure 5–33 shows the LVDS output with pre-emphasis.

Figure 5–33. Programmable Pre-Emphasis (1)



Note to Figure 5-33:

(1) V_P — voltage boost from pre-emphasis. V_{0D} — differential output voltage (peak–peak).

Table 5–18 lists the assignment name for programmable pre-emphasis and its possible values in the Quartus II software Assignment Editor.

Table 5–18. Q	uartus II Software	Assignment Editor—F	Programmable Pre-Emp	hasis
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Field	Assignment
То	tx_out
Assignment name	Programmable Pre-emphasis
Allowed values	0 (enable–default) and 1 (disable)

Differential Receiver

The receiver has a differential buffer and fractional PLLs that you can share among the transmitter and receiver, a data realignment block, and a deserializer.

The differential buffer can receive LVDS, mini-LVDS, and RSDS signal levels. You can statically set the I/O standard of the receiver pins to LVDS, mini-LVDS, or RSDS in the Quartus II software Assignment Editor.

The deserializer includes shift registers and parallel load registers, and sends a maximum of 10 bits to the internal logic.

Figure 5–34 shows the hardware blocks of the Cyclone V receiver.



Figure 5–34. Receiver Block Diagram ^{(1), (2)}

Notes to Figure 5-34:

- (1) In SDR and DDR modes, the data width from the IOE is 1 and 2 bits, respectively.
- (2) The rx_out port has a maximum data width of 10 bits.

Receiver Hardware Blocks

The differential receiver has the following hardware blocks:

- "Data Realignment Block (Bit Slip)"
- "Deserializer" on page 5–52

Data Realignment Block (Bit Slip)

Each receiver channel has a dedicated data realignment circuit that realigns the data by inserting bit latencies into the serial stream.

Skew in the transmitted data along with skew added by the link causes channel-to-channel skew on the received serial data streams.

The data realignment block compensates for the channel-to-channel skew and establishes the correct received word boundary at each channel.

An optional RX_CHANNEL_DATA_ALIGN port controls the bit insertion of each receiver independently controlled from the internal logic. The data slips one bit on the rising edge of RX_CHANNEL_DATA_ALIGN. The requirements for the RX_CHANNEL_DATA_ALIGN signal include:

- The minimum pulse width is one period of the parallel clock in the logic array.
- The minimum low time between pulses is one period of the parallel clock.
- The signal is an edge-triggered signal.
- The valid data is available two parallel clock cycles after the rising edge of RX_CHANNEL_DATA_ALIGN.

Figure 5–35 shows receiver output (RX_OUT) after one bit slip pulse with the deserialization factor set to 4.





The data realignment circuit can have up to 11 bit-times of insertion before a rollover occurs. The programmable bit rollover point can be from 1 to 11 bit-times, independent of the deserialization factor. Set the programmable bit rollover point equal to, or greater than, the deserialization factor—allowing enough depth in the word alignment circuit to slip through a full word. You can set the value of the bit rollover point using the MegaWizard Plug-In Manager. An optional status port, RX_CDA_MAX, is available to the FPGA fabric from each channel to indicate the reaching of the preset rollover point.

Figure 5–36 shows a preset value of four bit-times before rollover occurs. The rx_cda_max signal pulses for one rx_outclock cycle to indicate that rollover has occurred.

Figure 5–36. Receiver Data Realignment Rollover



Deserializer

You can statically set the deserialization factor to x4, x5, x6, x7, x8, x9, or x10 by using the Quartus II software.

The IOE contains two data input registers that can operate in DDR or SDR mode. You can bypass the Cyclone V deserializer in the Quartus II MegaWizard Plug-In Manager to support DDR (x2) or SDR (x1) operations, as shown Figure 5–37. You cannot use the data realignment circuit when you bypass the deserializer.

Figure 5–37. Deserializer Bypass ^{(1), (2), (3)}



Notes to Figure 5-37:

- (1) All disabled blocks and signals are grayed out.
- (2) In DDR mode, rx_inclock clocks the IOE register. In SDR mode, data is directly passed through the IOE.
- (3) In SDR and DDR modes, the data width from the IOE is 1 and 2 bits, respectively.

Receiver Modes

The Cyclone V device family supports the following receiver modes:

- LVDS Mode
- LVDS Direct Loopback Mode

LVDS Mode

Figure 5–38 shows the **LVDS** datapath block diagram. Input serial data is registered at the rising edge of the serial LVDS_diffioclk clock that is produced by the left and right PLLs.

You can select the rising edge option with the Quartus II MegaWizard Plug-In Manager.

Figure 5–38. Receiver Data Path in LVDS Mode (1), (2), (3)



Notes to Figure 5-38:

- (1) All disabled blocks and signals are grayed out.
- (2) In SDR and DDR modes, the data width from the IOE is 1 and 2 bits, respectively.

(3) The rx_out port has a maximum data width of 10 bits.

LVDS Direct Loopback Mode

LVDS direct loopback mode allows you to verify the **LVDS** driver and receiver pair by checking the incoming **LVDS** data from the true **LVDS** input buffer into the true **LVDS** output buffer.

The Cyclone V device family supports direct loopback mode for the **LVDS** driver and receiver pairs only in the same **LVDS** module. The **LVDS** module is a pair of receiver and transmitter pins that share the same LAB row or LAB column.

Figure 5–39 shows the true **LVDS** input and output buffer from an I/O pair from the same module.

Figure 5–39. LVDS Direct Loopback Path (1)



Note to Figure 5-39:

(1) The R_D value is pending characterization.

You can turn the **LVDS** direct loopback mode on or off with the assignment editor in the Quartus II software.

This option is available only for true differential I/O standards.

For example, you can apply the option on the **LVDS** output pair that is already being used in the design. Turning on the **LVDS** direct loopback mode option overrides the connection from the core with the signal from the true differential input buffer in the same I/O module. You can disable this option after verifying the **LVDS** driver receiver pair and recompiling your design.

Receiver Clocking

The fractional PLL receives the external clock input and generates different phases of the same clock.

The physical medium connecting the transmitter and receiver LVDS channels may introduce skew between the serial data and the source-synchronous clock. The instantaneous skew between each LVDS channel and the clock also varies with the jitter on the data and clock signals as seen by the receiver.

LVDS mode allows you to statically select the optimal phase between the source synchronous clock and the received serial data to compensate skew.

Differential I/O Termination

All I/O pins and dedicated clock input pins support R_D OCT.

You can enable on-chip termination in the Quartus II software Assignment Editor.

Table 5–19 lists the assignment name for $\rm R_{\rm D}$ OCT in the Quartus II software Assignment Editor.

Table 5–19. Quartus II Software Assignment Editor— R_D OCT

Field	Assignment
То	rx_in
Assignment name	Input Termination
Value	Differential

For more information, refer to "LVDS Input R_D OCT" on page 5–26.

Source-Synchronous Timing Budget

This section describes the timing budget, waveforms, and specifications for source-synchronous signaling in the Cyclone V device family.

The **LVDS** I/O standard enables high-speed transmission of data resulting in better overall system performance. To take advantage of the fast system performance, you must analyze the timing for these high-speed signals. Timing analysis for the differential block is different from traditional synchronous timing analysis techniques.

The basis of the source-synchronous timing analysis is the skew between the data and the clock signals instead of the clock-to-output setup times. High-speed differential data transmission requires the use of timing parameters provided by IC vendors and is strongly influenced by board skew, cable skew, and clock jitter.

Differential Data Orientation

There is a set relationship between an external clock and the incoming data. For operations at 840 Mbps and a serialization factor of 10, the external clock is multiplied by 10. You can set phase-alignment in the PLL to coincide with the sampling window of each data bit. The data is sampled on the falling edge of the multiplied clock.

Figure 5-40 shows the data bit orientation of the x10 mode.

Figure 5–40. Bit Orientation



Differential I/O Bit Position

Data synchronization is necessary for successful data transmission at high frequencies. The data bit orientation for a channel operation is based on the following conditions:

- The serialization factor is equal to the clock multiplication factor.
- The phase alignment uses edge alignment.
- The operation is implemented in hard SERDES.

Figure 5–41 shows the data bit orientation for a channel operation





Note to Figure 5-41:

(1) These waveforms are only functional waveforms and do not convey timing information.

For other serialization factors, use the Quartus II software tools to find the bit position within the word.

Table 5–20 lists the bit positions after deserialization.

Dessiver Channel Data Number	Internal 8-Bit Parallel Data			
Receiver channel Data Number	MSB Position	LSB Position		
1	7	0		
2	15	8		
3	23	16		
4	31	24		
5	39	32		
6	47	40		
7	55	48		
8	63	56		
9	71	64		
10	79	72		
11	87	80		
12	95	88		
13	103	96		
14	111	104		
15	119	112		
16	127	120		
17	135	128		
18	143	136		

Table 5–20. Differential Bit Naming

Transmitter Channel-to-Channel Skew

Transmitter channel-to-channel skew (TCCS) is the difference between the fastest and slowest data output transitions, including the T_{CO} variation and clock skew. For **LVDS** transmitters, the TimeQuest Timing Analyzer provides a TCCS report, which shows TCCS values for serial output ports.

The receiver skew margin (RSKM) calculation uses the TCCS—an important parameter based on the Cyclone V transmitter in a source-synchronous differential interface.

You can get the TCCS value from the TCCS report (report_TCCS) in the Quartus II compilation report in the TimeQuest Timing Analyzer or from the *Cyclone V Device Datasheet*.

Receiver Skew Margin for LVDS Mode

In LVDS mode, use RSKM, TCCS, and sampling window (SW) specifications for high-speed source-synchronous differential signals in the receiver data path.

For **LVDS** receivers, the Quartus II software provides an RSKM report showing the SW, time unit interval (TUI), and RSKM values for LVDS mode.

You can generate the RSKM report by executing the report_RSKM command in the TimeQuest Timing Analyzer. You can find the RSKM report in the Quartus II compilation report in the TimeQuest Timing Analyzer section.

If you do not set any input delay in the TimeQuest Timing Analyzer, the receiver channel-to-channel skew (RCCS) defaults to zero.

You can also directly set the input delay in a Synopsys Design Constraint file (.sdc) using the set_input_delay command.

For more information about the RSKM equation and calculation, refer to "Receiver Skew Margin for Non-DPA Mode" in the *LVDS SERDES Transmitter/Receiver* (*ALTLVDS_RX and ALTLVDS_TX*) *Megafunction User Guide*.

For more information about .sdc commands and to obtain the RKSM value from the TimeQuest Timing Analyzer, refer to *The Quartus II TimeQuest Timing Analyzer* chapter of the *Quartus II Development Software Handbook*.

Document Revision History

Table 5–21 lists the revision history for this chapter.

Table 5–21. Document Revision History

Date	Version	Changes
		Updated for the Quartus II software v12.0 release:
June 2012		 Restructured chapter.
	2.0	 Added "Design Considerations", "V_{CCIO} Restriction", "LVDS Channels", "Modular I/O Banks", and "OCT Calibration Block" sections.
		 Added Figure 5–3, Figure 5–4, Figure 5–5, Figure 5–6, and Figure 5–27.
		 Updated Table 5–1, Table 5–8, and Table 5–10.
		 Updated Figure 5–22 with emulated LVDS with external single resistor.
		 Updated Table 5–1, Table 5–2, Table 5–8, and Table 5–10.
February 2012	1.2	 Updated "I/O Banks" on page 5–8.
		 Minor text edits.
		Updated Table 5–2.
November 2011	1.1	 Updated Figure 5–3, Figure 5–4.
		 Updated "Sharing an OCT Calibration Block on Multiple I/O Banks", "High-Speed Differential I/O Interfaces", and "Fractional PLLs and Cyclone V Clocking" sections.
October 2011	1.0	Initial release.